











CSD13201W10

SLPS306A-MAY 2012-REVISED SEPTEMBER 2015

# **CSD13201W10 N-Channel NexFET™ Power MOSFET**

### **Features**

- Ultra-Low Qa and Qad
- Small Footprint (1 mm × 1 mm)
- Low Profile 0.62-mm Height
- Pb-Free
- **RoHS Compliant**
- Halogen-Free
- Gate-Source Voltage Clamp

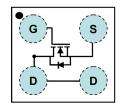
## **Applications**

- **Battery Management**
- Load Switch
- **Battery Protection**

## **Description**

This 12-V, 26-mΩ, N-Channel device is designed to deliver the lowest on resistance and gate charge in the smallest outline possible with excellent thermal characteristics in an ultra-low profile.

**Top View** 



#### **Product Summary**

T <sub>A</sub> = 25°	С	TYPICAL V	UNIT	
$V_{DS}$	Drain-to-Source Voltage	12		V
$Q_g$	Gate Charge Total (4.5 V)	2.3		nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain	0.3		nC
		V <sub>GS</sub> = 1.8 V	38	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On Resistance	V <sub>GS</sub> = 2.5 V	29	11122
	T to olota loo	$V_{GS} = 4.5 \text{ V}$	26	mΩ
V <sub>GS(th)</sub>	Threshold Voltage	0.8	V	

### Device Information<sup>(1)</sup>

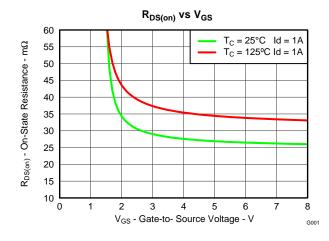
PART NUMBER	PACKAGE	MEDIA	QTY	SHIP
CSD13201W10	1 mm x 1 mm Wafer Level Package	7-inch reel	3000	Tape and Reel

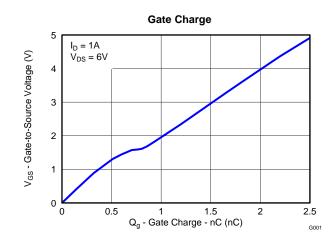
(1) For all available packages, see the orderable addendum at the end of the data sheet.

### **Absolute Maximum Ratings**

$T_A = 25^{\circ}C$	;	VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	12	V
$V_{GS}$	Gate-to-Source Voltage	±8	٧
I <sub>D</sub>	Continuous Drain Current, T <sub>A</sub> = 25°C <sup>(1)</sup>	1.6	Α
$I_{DM}$	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	20.2	Α
$P_D$	Power Dissipation <sup>(1)</sup>	1.2	W
T <sub>J</sub> , T <sub>stg</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C

- (1)  $R_{\theta JA} = 105^{\circ}\text{C/W}$  on  $1\text{in}^2$  Cu (2 oz.) on 0.060" thick FR4 PCB.
- (2) Pulse width ≤ 300 µs, duty cycle ≤ 2%







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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Original (May 2012) to Revision A	Pag	je
•	Added part number to title		1
•	Enhanced Description		1
•	Added Device and Documentation Support section.		7

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# 5 Specifications

## 5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC C	CHARACTERISTICS					
BV <sub>DSS</sub>	Drain-to-source voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	12			V
I <sub>DSS</sub>	Drain-to-source leakage current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 9.6 V			1	μΑ
I <sub>GSS</sub>	Gate-to-source leakage current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 8 V			100	nA
V <sub>GS(th)</sub>	Gate-to-source threshold voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.65	0.8	1.1	V
		$V_{GS} = 1.8 \text{ V}, I_D = 1 \text{ A}$		38	53	
R <sub>DS(on)</sub>	Drain-to-source on resistance	$V_{GS} = 2.5 \text{ V}, I_D = 1 \text{ A}$		29	39	$m\Omega$
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 1 A		26	34	
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 6 V, I <sub>D</sub> = 1 A		23		S
DYNAMIC	CHARACTERISTICS					
C <sub>ISS</sub>	Input capacitance			385	462	pF
Coss	Output capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 6 V, f = 1 MHz		245	294	pF
C <sub>RSS</sub>	Reverse transfer capacitance			18.1	22.6	pF
R <sub>g</sub>	Series gate resistance			3		Ω
Qg	Gate charge total (4.5 V)			2.3	2.9	nC
Q <sub>gd</sub>	Gate charge gate-to-drain	V <sub>DS</sub> = 6 V, I <sub>D</sub> = 1 A		0.3		nC
Q <sub>gs</sub>	Gate charge gate-to-source	$V_{DS} = 6 \text{ V}, I_D = 1 \text{ A}$		0.5		nC
Q <sub>g(th)</sub>	Gate charge at Vth			0.3		nC
Q <sub>OSS</sub>	Output charge	V <sub>DS</sub> = 6.0 V, V <sub>GS</sub> = 0 V		1.8		nC
t <sub>d(on)</sub>	Turn on delay time			3.9		ns
t <sub>r</sub>	Rise time	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 1 A		5.9		ns
t <sub>d(off)</sub>	Turn off delay time	$R_G = 20 \Omega$		14.4		ns
t <sub>f</sub>	Fall time			9.7		ns
DIODE C	HARACTERISTICS					
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> = 1 A, V <sub>GS</sub> = 0 V		0.7	1	V
Q <sub>rr</sub>	Reverse recovery charge	\/ C\/   4 A di/d+ 400 A/		2.4		nC
t <sub>rr</sub>	Reverse recovery time	$V_{DS}$ = 6 V, $I_{S}$ = 1 A, di/dt = 100 A/ $\mu$ s		11.5		ns

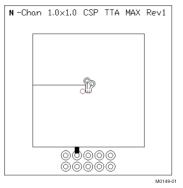
## 5.2 Thermal Information

(T<sub>A</sub> = 25°C unless otherwise stated)

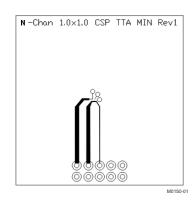
	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Thermal resistance junction-to-ambient (minimum Cu area)			228.6	°C/W
$R_{\theta JA}$	Thermal resistance junction-to-ambient (1 in <sup>2</sup> Cu area)			131.1	°C/W

Product Folder Links: CSD13201W10





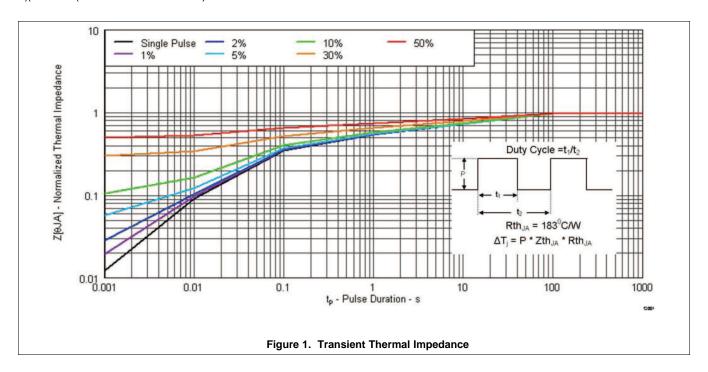
Max  $R_{\theta JA} = 131.1^{\circ}$ C/W when mounted on 1 inch<sup>2</sup> of 2 oz. Cu.



Max  $R_{\theta JA} = 228.6$  °C/W when mounted on minimum pad area of 2 oz. Cu.

# 5.3 Typical MOSFET Characteristics

 $T_A = 25$ °C (unless otherwise noted)



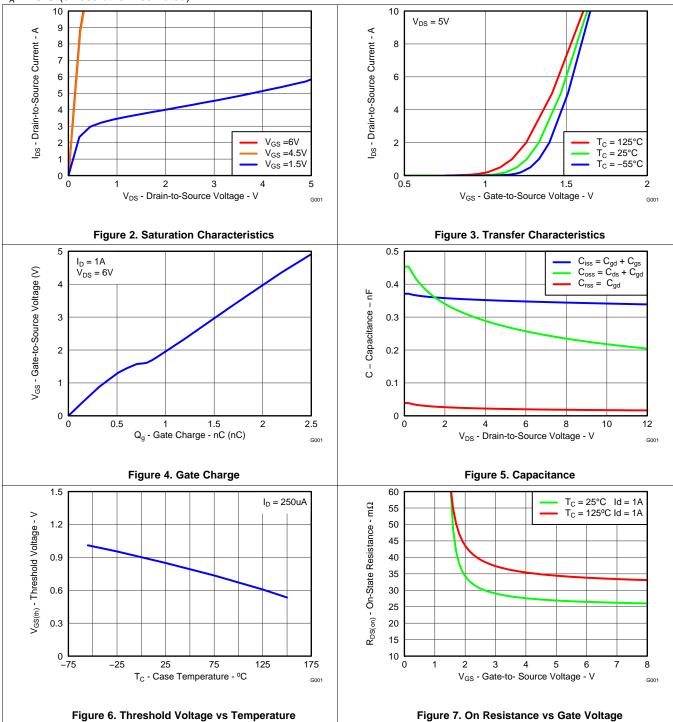
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## **Typical MOSFET Characteristics (continued)**

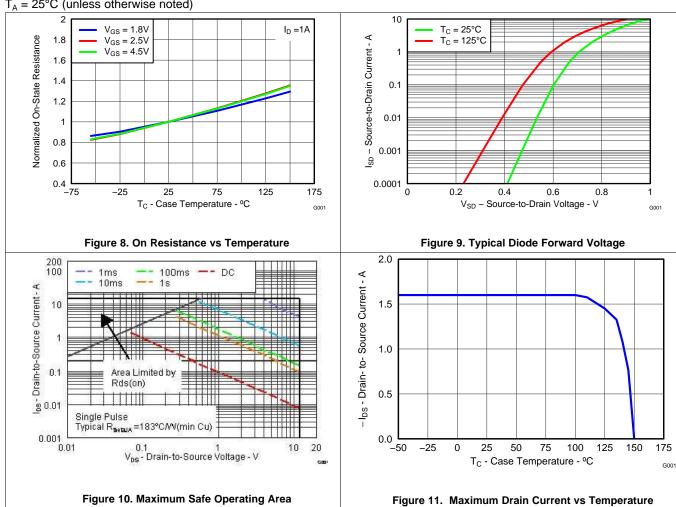
 $T_A = 25$ °C (unless otherwise noted)





### **Typical MOSFET Characteristics (continued)**

 $T_A = 25$ °C (unless otherwise noted)





## 6 Device and Documentation Support

#### 6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 6.2 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

#### 6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

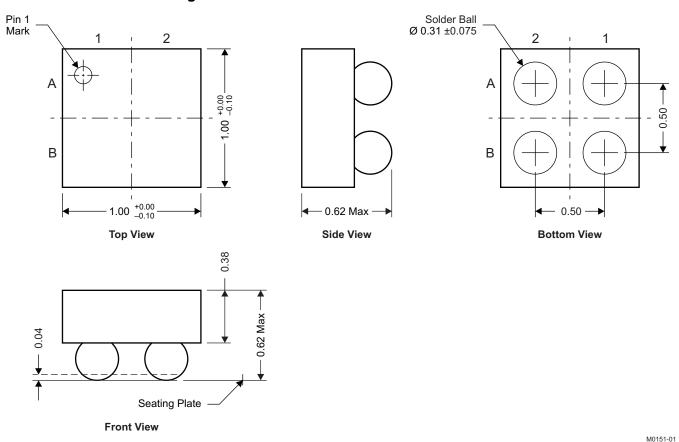
Product Folder Links: CSD13201W10



# 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

#### 7.1 CSD13201W10 Package Dimensions



NOTE: All dimensions are in mm (unless otherwise specified)

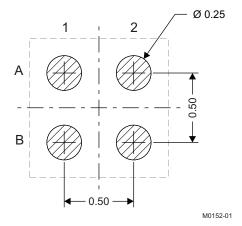
**Pin Configuration Table** 

POSITION	DESIGNATION
A2	Source
A1	Gate
B1, B2	Drain

Product Folder Links: CSD13201W10

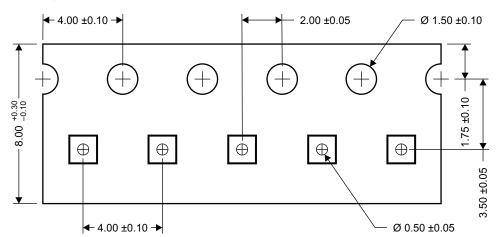


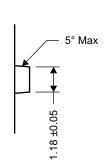
### 7.2 Land Pattern Recommendation



NOTE: All dimensions are in mm (unless otherwise specified)

## 7.3 Tape and Reel Information







M0153-01

NOTE: All dimensions are in mm (unless otherwise specified)



## PACKAGE OPTION ADDENDUM

23-Aug-2015

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD13201W10	ACTIVE	DSBGA	YZB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-55 to 150	201	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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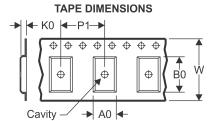
23-Aug-2015

## PACKAGE MATERIALS INFORMATION

www.ti.com 30-Apr-2018

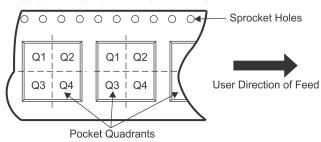
## TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD13201W10	DSBGA	YZB	4	3000	180.0	8.4	1.06	1.06	0.69	4.0	8.0	Q1

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 30-Apr-2018

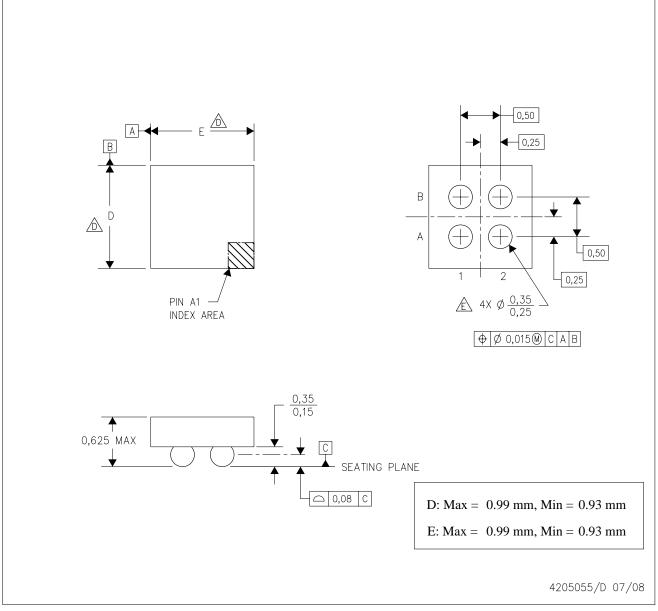


#### \*All dimensions are nominal

Device	Package Type	Package Drawing	SPQ	Length (mm)	Width (mm)	Height (mm)	
CSD13201W10	DSBGA	YZB	4	3000	182.0	182.0	20.0

# YZB (S-XBGA-N4)

### DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- Devices in YZB package can have dimension D ranging from 0.94 to 1.65 mm and dimension E ranging from 0.94 to 1.65 mm.

  To determine the exact package size of a particular device, refer to the device datasheet or contact a local TI representative.
- E. Reference Product Data Sheet for array population. 2 x 2 matrix pattern is shown for illustration only.
- F. This package contains lead—free balls. Refer to YEB (Drawing #4204178) for tin—lead (SnPb) balls.



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